## 國立暨南國際大學 106 學年度碩士班入學考試試題

科目:電子學二(電路)

適用:電機系

1.依次序作答,只要標明題號,不必抄題。

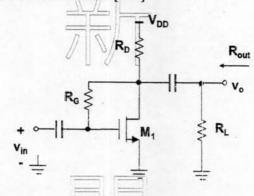
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編號:352

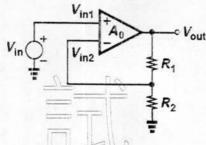
2.答案必須寫在答案卷上,否則不予計分。 3.限用藍、黑色筆作答;試題須隨卷繳回。

1. Assume the capacitors in the circuit shown below are sufficiently large so as to act as short circuits at the signal frequencies of interest.  $V_{DD} = 1.5 \text{V}$ .  $R_G = 1 \text{M}\Omega$ ,  $R_D = 4 \text{K}\Omega$ ,  $R_L = 4K\Omega$ .  $M_1$  has  $V_{tn} = 0.5V$ ,  $\mu_n C_{ox}(W/L)_1 = 0.4 \text{mA/V}^2$ , and  $\lambda = 0.5 \text{V}^{-1}$ .

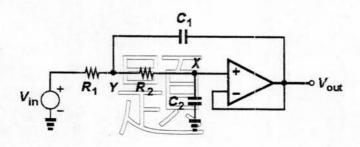
- (a) Find the DC operating point (IDS, VDS). [5%]
- (b) Draw the small-signal equivalent circuit. [5%]
- (c) Determine the voltage gain  $A_v = v_o/v_{in}$ . [5%]
- (d) Determine the output resistance Rout. [5%]



- 2. For the non-inverting amplifier shown below,
  - (a) Derive its voltage gain,  $A_v = V_{out}/V_{in}$ , if  $A_0 = \infty$ , [5%]
  - (b) Derive its voltage gain,  $A_v = V_{out}/V_{in}$ , if  $A_0 \neq \infty$ . [5%]
  - (c) What is its gain error if  $R_1/R_2 = 4$ , and  $A_0 = 1000$ . [5%]



- 3. Assume the open-loop gain of the op-amp in the circuit below is infinite.
  - (a) Derive the transfer function,  $H(s) = V_{out}(s)/V_{in}(s)$ . [5%]
  - (b) Assume the second pole is much smaller than the first one. What are these poles? [5%]



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考生注意

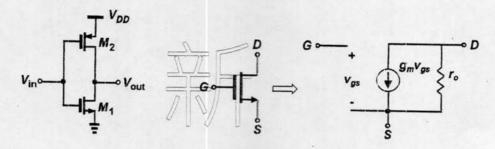
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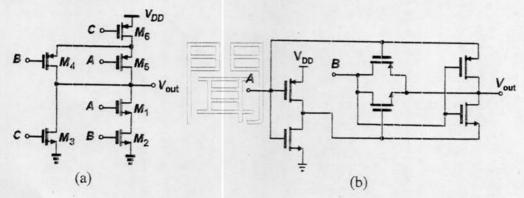
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4. A CMOS inverter amplifier and sma'l-signal equivalent circuit model of NMOS are shown below. Assume  $M_1$  and  $M_2$  have been properly biased at saturation region.

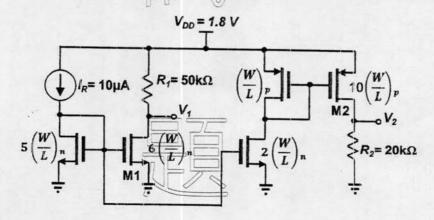
- (a) Draw the small-signal equivalent circuit for the inverter amplifier. [5%]
- (b) Derive the voltage gain,  $A_v = V_{out}/V_{in}$ . [5%]



 Assume all MOSs in the following two circuits are ideal switches. Determine their logic functions. [10%]



- 6. A current mirror application is shown below, where (W/L) is the ratio of width to length of MOS's. The drain-source voltage of MOS, |Vos|, must be larger than 0.2V for good mirroring in the application.
  - (a) Determine the voltage values of V1 and V2. [5%]
  - (b) Find the maximum  $I_R$  that keeps both M1 and M2 saturation for good mirroring. [5%]



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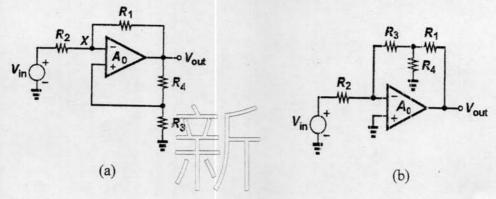
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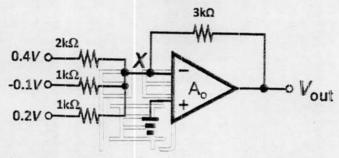
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7. Determine the closed-loop gain of the following two circuits if  $A_0 = \infty$ . [10%]



8. Find  $V_{\text{out}}$  for the circuit shown below if  $A_0 = \infty$ . [5%]



- 9. (a) Determine the input impedance,  $Z_{in}$ , for the circuit shown below. Assume  $\lambda = 0$  [5%]
  - (b) At what condition  $|Z_{in}|$  behaves as an inductance? [5%]

